NSN 5962-01-088-1635

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View Online at https://aerobasegroup.com/nsn/5962-01-088-1635

Body Length:

Between 2.030 inches and 2.080 inches

Body Width:

Between 0.515 inches and 0.600 inches

Body Height:

Between 0.145 inches and 0.175 inches

Maximum Power Dissipation Rating:

1.5 watts

Operating Tempurature Range:

+0.0/+85.0 degrees celsius

Storage Tempurature Range:

-55.0/+125.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and positive outputs and high speed and w/enable and programmable and resettable and 3-state output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

14 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

400.00 nanoseconds propagation delay time, low to high level output and 400.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Ram

Memory Capacity:

Unknown

Test Data Document:

30003-810as824 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

40 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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